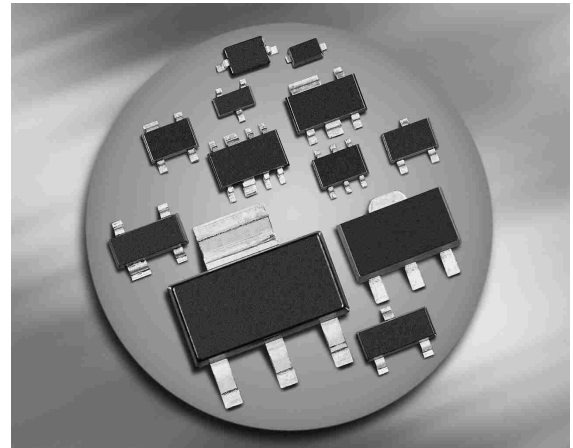
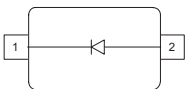


Silicon Schottky Diode

- High current rectifier Schottky diode with very low V_F drop (typ. 0.24 V at $I_F = 10\text{mA}$)
- For power supply applications
- For clamping and protection in low voltage applications
- For detection and step-up-conversion



BAT60B



ESD: Electrostatic discharge sensitive device, observe handling precaution!

| Type | Package | Configuration | Marking |
|--------|---------|---------------|---------|
| BAT60B | SOD323 | single | white/5 |

Maximum Ratings at $T_A = 25^\circ\text{C}$, unless otherwise specified

| Parameter | Symbol | Value | Unit |
|---|-----------|-------------|------|
| Diode reverse voltage ¹⁾ | V_R | 10 | V |
| Forward current | I_F | 3 | A |
| Non-repetitive peak surge forward current ($t \leq 10\text{ms}$) | I_{FSM} | 5 | |
| Total power dissipation $T_S \leq 28^\circ\text{C}$ | P_{tot} | 1350 | mW |
| Junction temperature | T_j | 150 | °C |
| Operating temperature range | T_{op} | -55 ... 125 | |
| Storage temperature | T_{stg} | -55 ... 150 | |

Thermal Resistance

| Parameter | Symbol | Value | Unit |
|--|------------|-----------|------|
| Junction - soldering point ²⁾ | R_{thJS} | ≤ 90 | K/W |

¹For $T_A > 25^\circ\text{C}$ the derating of V_R has to be considered. Please refer to curve Permissible reverse voltage.

²For calculation of R_{thJA} please refer to Application Note Thermal Resistance

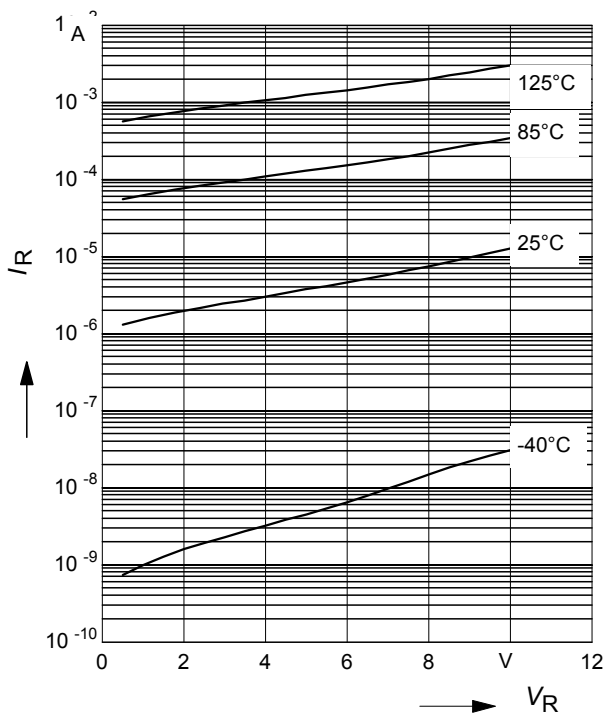
Electrical Characteristics at $T_A = 25^\circ\text{C}$, unless otherwise specified

| Parameter | Symbol | Values | | | Unit |
|--|--------|--------|------|------|---------------|
| | | min. | typ. | max. | |
| DC Characteristics | | | | | |
| Reverse current ¹⁾ | I_R | | | | μA |
| $V_R = 5\text{ V}$ | | - | 5 | 15 | |
| $V_R = 8\text{ V}$ | | - | 10 | 25 | |
| $V_R = 5\text{ V}, T_A = 80^\circ\text{C}$ | | - | 100 | 800 | |
| $V_R = 8\text{ V}, T_A = 80^\circ\text{C}$ | | - | 410 | 1500 | |
| Forward voltage ¹⁾ | V_F | | | | V |
| $I_F = 10\text{ mA}$ | | 0.2 | 0.24 | 0.3 | |
| $I_F = 100\text{ mA}$ | | 0.26 | 0.32 | 0.38 | |
| $I_F = 500\text{ mA}$ | | 0.32 | 0.4 | 0.5 | |
| $I_F = 1000\text{ mA}$ | | 0.36 | 0.48 | 0.6 | |
| AC Characteristics | | | | | |
| Diode capacitance | C_T | 12 | 25 | 30 | pF |
| $V_R = 5\text{ V}, f = 1\text{ MHz}$ | | | | | |

¹⁾Pulsed test: $t_p = 300\ \mu\text{s}; D = 0.01$

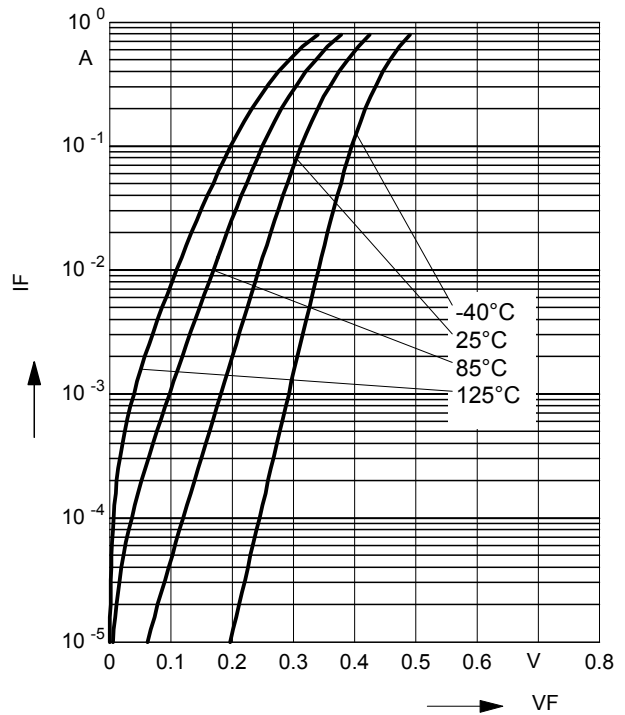
Reverse current $I_R = f(V_R)$

$T_A =$ Parameter



Forward current $I_F = f(V_F)$

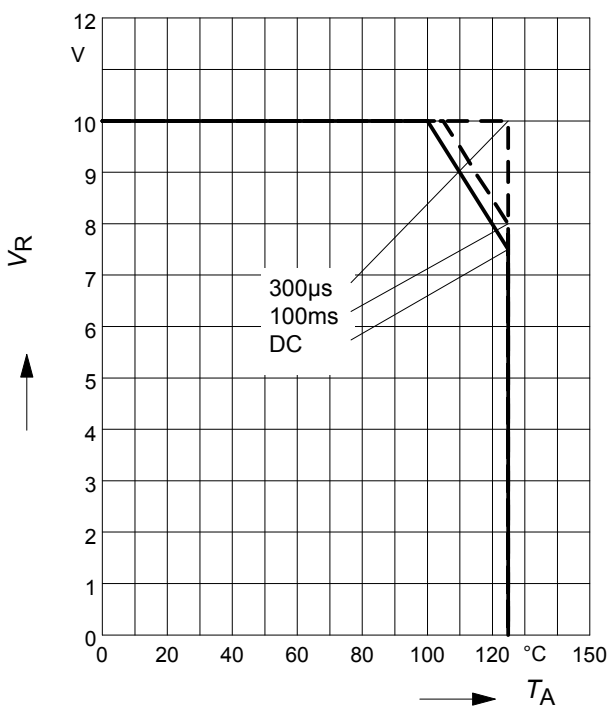
$T_A =$ Parameter



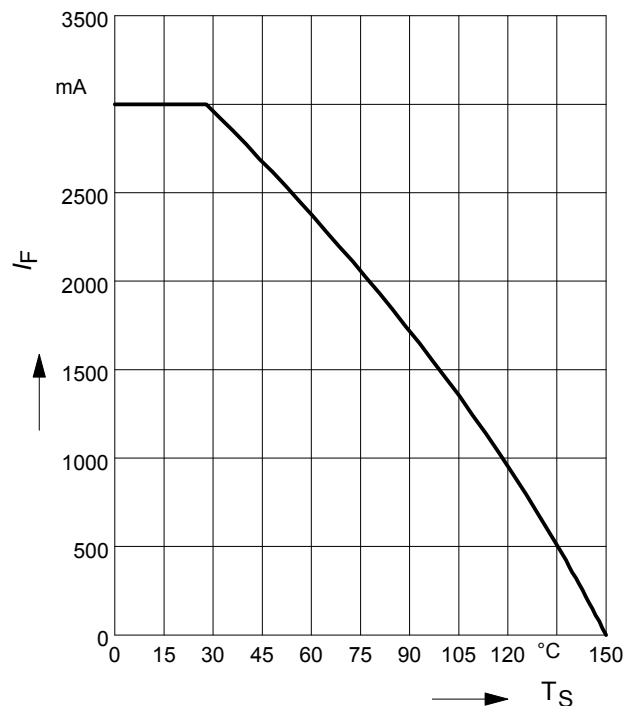
Permissible Reverse voltage $V_R = f(T_A)$

$t_p =$ Parameter; duty cycle < 0.01

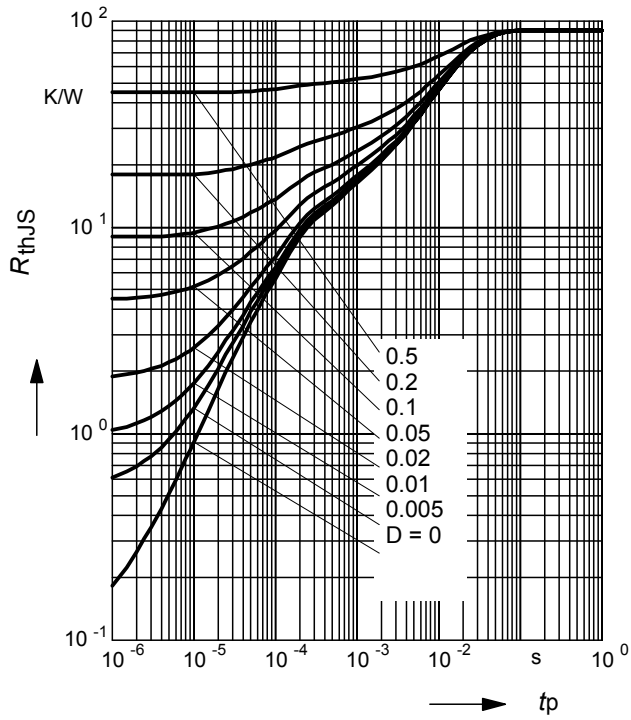
Device mounted on PCB with $R_{th} = 160$ K/W



Forward current $I_F = f(T_S)$

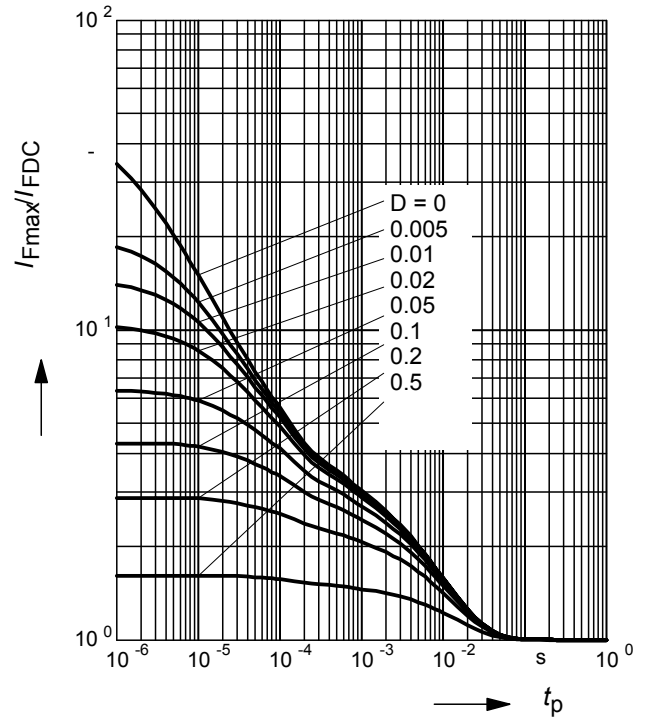


Permissible Puls Load $R_{thJS} = f(t_p)$



Permissible Pulse Load

$I_{Fmax} / I_{FDC} = f(t_p)$



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